


REVISIONS																			
LTR	DESCRIPTION										DATE (YR-MO-DA)				APPROVED				
A	Add one vendor, CAGE 06665. Make changes to table I and throughout the drawing. Remove one vendor, CAGE 34333.										90-02-01				M. A. Frye				
B	Add device type 02. Add case outlines G and P. Table I changes. Add one vendor, CAGE 64155. Editorial changes throughout.										94-08-09				M. A. Frye				
C	Make change to VOL1 test as specified in table I. - ro										99-06-10				R. Monnin				
D	Add case outline Z and CAGE 27014. - ro										01-02-22				R. Monnin				
E	Drawing updated to reflect current requirements. - ro										06-01-10				R. Monnin				
F	Update drawing to current MIL-PRF-38535 requirements. -rrp										14-02-24				C. Saffle				
G	Redraw. Update paragraphs to MIL-PRF-38535 requirements. - drw										19-04-18				Charles F. Saffle				



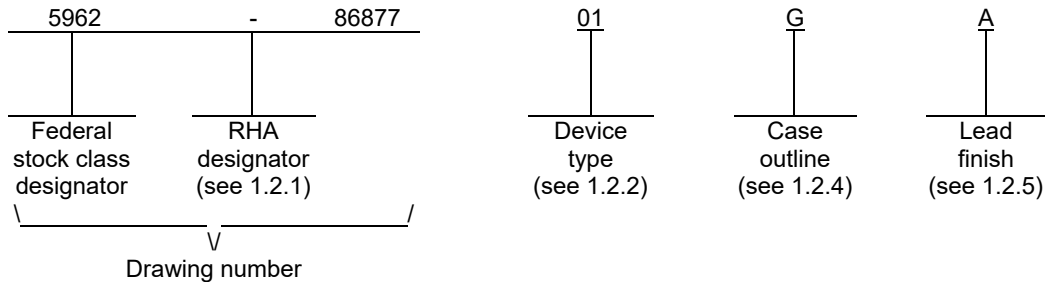
REV																			
SHEET																			
REV																			
SHEET																			
REV STATUS	REV			G	G	G	G	G	G	G	G	G	G	G	G				
OF SHEETS	SHEET			1	2	3	4	5	6	7	8	9	10	11					
PMIC N/A				PREPARED BY Donald R. Osbourne				DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 https://www.dla.mil/landandmaritime											
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY D. A. DiGenzo															
				APPROVED BY N. A. Hauck															
				DRAWING APPROVAL DATE 87-07-15															
				REVISION LEVEL G				SIZE A	CAGE CODE 67268		5962-86877								
												SHEET 1 OF 11							

1. SCOPE

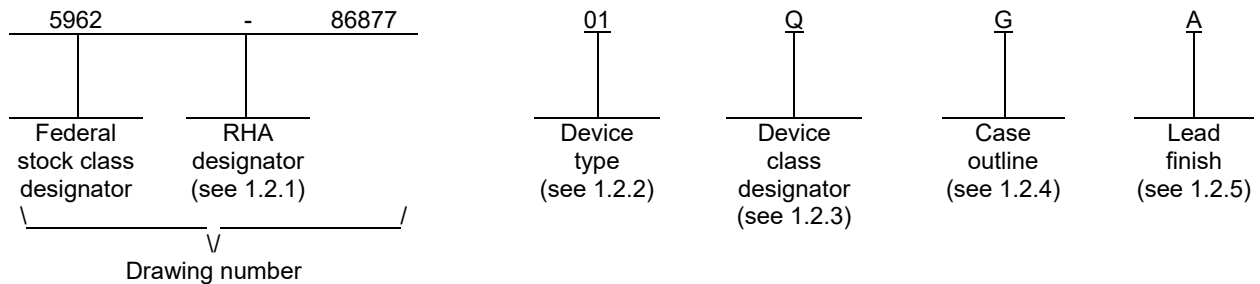
1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device class Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following examples:

For device class M and Q:



For device class V:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device types. The device types identify the circuit function as follows:

Device type	Generic number	Circuit function
01	PM111, LM111	Precision voltage comparator / buffer
02	LT111A	Precision voltage comparator / buffer

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A
Q or V	Certification and qualification to MIL-PRF-38535

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
G

5962-86877

SHEET
2

1.2.4 Case outlines. The case outlines are as designated in MIL-STD-1835 as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
G	MACY1-X8	8	Can
P	GDIP1-T8 or CDIP2-T8	8	Dual-in-line
Z	GDFP1-G10	10	Flat pack with gull wing leads
2	CQCC1-N20	20	Square leadless chip carrier

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

1.3 Absolute maximum ratings. 1/

Ground to negative supply voltage	-30.0 V
Total supply voltage (V+ to V-)	±36.0 V
Output to negative supply voltage	-50.0 V
Input voltage	±15 V 2/
Differential input voltage	±30.0 V
Output sink current	50 mA
Output short circuit duration	10 seconds
Maximum strobe current	10 mA
Power dissipation (PD)	500 mW
Storage temperature range	-65°C to +150°C
Junction temperature (TJ)	+175°C 3/
Lead temperature (soldering, 60 seconds)	+300°C
Thermal resistance, junction-to-case (θJC):	
Cases G, P, and 2	See MIL-STD-1835
Case Z	24°C/W

1.4 Recommended operating conditions.

Supply voltage (Vs)	±15 V
Ambient operating temperature range (TA)	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 2/ Rating applies to Vs = ±15 V. The positive input voltage limit is 30 V above the negative supply. The negative input voltage limit is equal to the negative supply voltage or 30 V below the positive supply, whichever is less negative.
- 3/ For short term test (in the specific burn-in and life test configuration when required and up to 138 hours maximum)
TJ = +275°C.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 3

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <https://quicksearch.dla.mil>).

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 as specified herein, or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline. The case outline shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DLA Land and Maritime-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.

3.9 Verification and review for device class M. For device class M, DLA Land and Maritime, DLA Land and Maritime's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 50 (see MIL-PRF-38535, appendix A).

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 4

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions <u>1/</u> , <u>2/</u> -55°C ≤ TA ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V _{IO}	RS = 50Ω, VIC = 0 V, 13 V, and -14.5 V	1	01		±3.0	mV
			2, 3			±4.0	
			1	02		±1.0	
			2, 3			±2.0	
		RS = 50Ω, VIC = 0 V, VS = ±2.5 V	1	01		±3.0	
			2, 3			±4.0	
			1	02		±1.0	
			2, 3			±2.0	
Raised input offset <u>3/</u> voltage	V _{IO(R)}	RS = 50Ω, VIC = 0 V, 13 V, and -14.5 V, VBAL = VBAL/STB = V+	1	01		±3.0	mV
				02		±1.0	
			2, 3	01		±4.5	
				02		±2.5	
Input offset voltage temperature coefficient	ΔV _{IO} / ΔT	RS = 50Ω <u>4/</u>	2, 3	01, 02		±25	μV/°C
Input offset current	I _{IO}	VIC = 0 V, 13 V, and -14.5 V	1, 2	01		±10	nA
			3			±20	
			1, 2	02		±5	
			3			±10	
Raised input offset <u>3/</u> current	I _{IO(R)}	VIC = 0 V, VBAL = VBAL/STB = V+	1, 2	01, 02		±25	nA
			3			±50	
Input offset current temperature coefficient	ΔI _{IO} /ΔT	+25°C to +125°C <u>4/</u>	1, 2	01, 02		±100	pA/°C
		+25°C to -55°C <u>4/</u>	1, 3			±200	

See footnotes at end of table.

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
G

5962-86877

SHEET
5

TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions <u>1/</u> , <u>2/</u> -55°C ≤ TA ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Input bias current	+IIB	VIC = 0 V	1, 2	All	-100	+0.1	nA
			3		-150	+0.1	
		VIC = 13 V and -14.5 V	1, 2		-150	+0.1	
			3		-200	+0.1	
	-IIB	VIC = 0 V	1, 2	All	-100	+0.1	
			3		-150	+0.1	
		VIC = 13 V and -14.5 V	1, 2		-150	+0.1	
			3		-200	+0.1	
Collector output voltage (STROBED)	VO(STB)	RS = 50Ω, ISTB = -3.0 mA	1, 2, 3	All	14		V
Common mode rejection	CMR	RS = 50Ω, VIC = 13 V and -14.5 V	1, 2, 3	All	80		dB
Output leakage current	ICEX	VS = ±18 V, VIN = 5 mV, VO = 32 V	1	All	-1	10	nA
			2		-1	500	
Input leakage current	II1	VS = ±18 V, VID = -29 V	1, 2, 3	All	-5	500	nA
	II2	VS = ±18 V, VID = -29 V			-5	500	
Positive supply current	I+		1	All		6.0	mA
			2			6.0	
			3			7.0	
Negative supply current	I-		1	All		-5.0	mA
			2			-5.0	
			3			-6.0	
Output short circuit current	IOS	10 ms maximum test duration	1	All	0	200	mA
			2		0	150	
			3		0	250	

See footnotes at end of table.

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
G

5962-86877

SHEET
6

TABLE I. Electrical performance characteristics – continued.

Test	Symbol	Conditions <u>1/</u> , <u>2/</u> -55°C ≤ TA ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Adjustment for input offset voltage	V _{IO} (ADJ)+	R _S = 50Ω, T _A = +25°C	1	All	+5.0		mV
	V _{IO} (ADJ)-				-5.0		
Low level output voltage	VOL1	V ₊ = 4.5 V, V ₋ = 0 V, V _{IC} = 0.71 V, I _O = 8 mA, V _{ID} = -6.0 mV	1, 2, 3	All	0	0.4	V
	VOL2	V ₊ = 4.5 V, V ₋ = 0 V, V _{IC} = -1.75 V, I _O = 8 mA, V _{ID} = -6.0 mV			0	0.4	
Low level output voltage	VOL3	V _S = ±15 V, V _{ID} = -5.0 mV, V _{IC} = 13 V, I _O = 50 mA	1, 2, 3	All	0	1.5	V
	VOL4	V _S = ±15 V, V _{ID} = -5.0 mV, V _{IC} = -14 V, I _O = 50 mA			0	1.5	
Voltage gain (emitter output)	+AVE	R _L = 600Ω	4	All	10		V/mV
			5, 6		8		
Response time, low-to- high, collector output	t _{RLHC}	V _{OD} (overdrive) = -5 mA, C _L = 50 pF(min), V _{IN} = 100 mV	7, 8B	All	0	300	ns
			8A		0	640	
Response time, high-to- low collector output	t _{RHLC}	V _{OD} (overdrive) = +5 mA, C _L = 50 pF(min), V _{IN} = 100 mV	7, 8B	All	0	300	ns
			8A		0	500	

1/ Unless otherwise specified, V_{IC} = 0 V and V_S = ±15 V.

2/ V_{IC} is achieved by algebraically subtracting the common mode voltage from each V_S (power supplies) and algebraically adding it to V_{IN}. V_{IC} can be calculated by using the following formula:

$$V_{IC} = -[(V_{+}) + (V_{-})] / 2 + V_{IN}$$

3/ Subscript (R) indicates tests which are performed with input stage current raised by connecting BAL and BAL/STB terminals to V₊.

4/ If not tested, shall be guaranteed to the limits specified in table I herein.

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
G

5962-86877

SHEET
7

Device types	01 and 02		
Case outlines	G and P	Z	2
Terminal number	Terminal symbol		
1	GROUND	GND	NC
2	IN+	IN+	EMIT OUT
3	IN-	IN-	NC
4	V-	NC	NC
5	BALANCE	V-	IN+
6	BAL / STRB	BALANCE	NC
7	OUT	BAL / STRB	IN-
8	V+	NC	NC
9	---	OUTPUT	NC
10	---	V+	V-
11	---	---	NC
12	---	---	BALANCE
13	---	---	NC
14	---	---	NC
15	---	---	BAL / STRB
16	---	---	NC
17	---	---	COL OUT
18	---	---	NC
19	---	---	NC
20	---	---	V+

NC = No connection, no external connection should be made to these pins.

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 8

4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}\text{C}$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections, and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 9

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 9, 10 and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1	1	1
Final electrical parameters (see 4.2)	1, 2, 3, 4, 5, 6, <u>1/</u> 7, 8A, 8B	1, 2, 3, 4, 5, 6, <u>1/</u> 7, 8A, 8B	1, 2, 3, 4, 5, 6, <u>2/</u> 7, 8A, 8B
Group A test requirements (see 4.4)	1, 2, 3, 4, 5, 6, 7, 8A, 8B	1, 2, 3, 4, 5, 6, 7, 8A, 8B	1, 2, 3, 4, 5, 6, 7, 8A, 8B
Group C end-point electrical parameters (see 4.4)	1	1	1
Group D end-point electrical parameters (see 4.4)	1	1	1
Group E end-point electrical parameters (see 4.4)	---	---	---

1/ PDA applies to subgroup 1.

2/ PDA applies to subgroups 1 and 7.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
- b. $T_A = +125^{\circ}\text{C}$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 10

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table II herein.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.1.2 Substitutability. Device class Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed in MIL-HDBK-103 and QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DLA Land and Maritime-VA.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-86877
		REVISION LEVEL G	SHEET 11

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 19-04-18

Approved sources of supply for SMD 5962-86877 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <https://landandmaritimeapps.dla.mil/programs/smcr/>.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /	Reference military specification PIN
5962-8687701GA	57300	MTLM111QH	M38510/10304BGA
	<u>3</u> /	AS111T008/883C	
	<u>3</u> /	LM111H/883	
5962-8687701PA	57300	MTLM111QD8	M38510/10304BPA
	<u>3</u> /	AS111C008/883C	
	<u>3</u> /	LM111J8/883	
	<u>3</u> /	PM111RC	
5962-86877012A	57300	MTLM111QLS	M38510/10304B2A
	<u>3</u> /	AS111E020/883C	
	<u>3</u> /	PM111RCMDA	
5962-8687702GA	57300	MTLT111AQH	---
	<u>3</u> /	LT111AH/883	
5962-8687702PA	57300	MTLT111AQD8	---
	<u>3</u> /	LT111AJ8/883	
5962-86877022A	57300	MTLT111AQLS	---
5962-8687701QGA	<u>3</u> /	LM111H-SMD	M38510/10304BGA
5962-8687701QPA	<u>3</u> /	LM111J-8-SMD	M38510/10304BPA
5962-8687701QZA	<u>3</u> /	LM111WG-SMD	---
5962-8687701Q2A	<u>3</u> /	LM111E-SMD	M38510/10304B2A

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.

2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

3/ Not available from an approved source of supply.

STANDARD MICROCIRCUIT DRAWING BULLETIN - continued

DATE: 19-04-18

Vendor CAGE
number

57300

Vendor name
and address

Micross Components
7725 N. Orange Blossom Trail
Orlando, FL 32810-2696

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.